



TO-92S Plastic-Encapsulate Transistors

KSC2785 TRANSISTOR (NPN)

FEATURES

- Complement to KSA1175
- High Transition Frequency

TO – 92S

1. Emitter
2. Collector
3. Base



MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

| Symbol | Parameter | Value | Unit |
|------------------|---|----------|------|
| V _{CBO} | Collector-Base Voltage | 60 | V |
| V _{CEO} | Collector-Emitter Voltage | 50 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| I _c | Collector Current | 0.15 | A |
| P _c | Collector Power Dissipation | 250 | mW |
| R _{θJA} | Thermal Resistance From Junction To Ambient | 500 | °C/W |
| T _j | Junction Temperature | 150 | °C |
| T _{stg} | Storage Temperature | -55~+150 | °C |

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

| Parameter | Symbol | Test conditions | Min | Typ | Max | Unit |
|--------------------------------------|----------------------|--|-----|-----|-----|------|
| Collector-base breakdown voltage | V _{(BR)CBO} | I _c = 0.1mA, I _e =0 | 60 | | | V |
| Collector-emitter breakdown voltage | V _{(BR)CEO} | I _c =10mA, I _b =0 | 50 | | | V |
| Emitter-base breakdown voltage | V _{(BR)EBO} | I _e =0.01mA, I _c =0 | 5 | | | V |
| Collector cut-off current | I _{CBO} | V _{CB} =40V, I _e =0 | | | 0.1 | μA |
| Emitter cut-off current | I _{EBO} | V _{EB} =3V, I _c =0 | | | 0.1 | μA |
| DC current gain | h _{FE} | V _{CE} =6V, I _c =1mA | 70 | | 700 | |
| Collector-emitter saturation voltage | V _{CE(sat)} | I _c =100mA, I _b =10mA | | | 0.3 | V |
| Collector output capacitance | C _{ob} | V _{CB} =6V, I _e =0, f=1MHz | | 2.5 | | pF |
| Transition frequency | f _T | V _{CE} =6V, I _c =10mA | | 300 | | MHz |

CLASSIFICATION OF h_{FE}

| RANK | O | Y | G | L |
|-------|--------|---------|---------|---------|
| RANGE | 70-140 | 120-240 | 200-400 | 350-700 |